

Sr⁹⁰ tests of DOI Samples

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Samples



Doi 953, 270 µm

Doi 954, 265 µm

2x1 mm pad metallisation from microbeam tests3 Al pads and 3 Cr+Au pads



Samples





Samples mounted in frames, all pads connected together on substrate side. Pads Au1 and Al3 connected individually, pads Au2, Au3 and Al1, Al2 connected together.

Charge collection efficiency measured on Sr⁹⁰ setup in Zeuthen Due to technical difficulties (collimation and leakage currents over the edges) and limited time only pads Au1 and Al3 were measured.



DOI 953



Negative branch corresponds to -HV applied to substrate

Pad Au1 shows CCE ~ 55% @ 400V, not completely saturated
Voltage limited by increase in noise at higher voltages
Pad Al3 demonstrates very strong polarisation and much lower signals
Either metallisation or non-homogeneity of the sample.



DOI 954



Similar results for negative branch, both asymmetric. Could be field configuration. CCE ~55% @ 300V, again limited by increased noise at higher voltages.





DOI 954



Measurements of 954 with previous metallisation.

Results are similar to the current measurements Faster CCE saturation with alternating voltage suggests that there are some polarisation effects





Both samples 953 and 954 demonstrate CCE up to 60% There is a difference between pad – either because of inhomogeneity or metallisation

All pads demonstrate polarisation behavior to some extent

Strange thing – after switching off HV signals of both polarities could be seen.



Influence of illumination on radiation damaged single crystal diamond charge collection efficiency



Diamond – So14-04, SC CVD by E6, irradiated to 5 MGy @ 2007 + 5 MGy more @ 2008 => Total ~10MGy by 10MeV electrons

Thickness 325 um





Diamond was "reset" by UV lamp for ~ 20 min before the first measurement. CCE was measured over time. @ 300V

So14-10 325 um



After switching on HV and source: Fast (few minutes) increase in CCE Relatively slow decrease in CCE over next 20-30 minutes Stable signal



Illumination

Same process with illumination by red LED (635nm, 1.95eV)



Slow (~20-30 min) increase in CCE to 60% from stable 23% Stable effect over 10 hours Steps are testt of different light intensities



Illumination



Effect depends on the intensity of light

There is a saturated value

Saturation is at similar power for two samples with order of magnitude difference in damage, i.e. does not depend on damage.

Amount of recovered CCE close to 2.5 times "stable" value for both

¹⁹⁻Nov-14



CCE vs HV



CCE vs HV still looks like it should for damaged diamond – no CCE saturation at low voltages (was ~100% @ 80V before irradiation)



Infrared



940nm IR LED (1.32 eV) there is an effect, but smaller



Green



520nm green LED (2.38 eV) – saturated at high intensities Peak at low intensities, not as high as red



Blue



465nm blue LED (2.67 eV) – similar to green, but saturated value is lower than initial. Also, leakage current increases at high intensities. No increase in current observed for undamaged diamond



Ultra violet



365nm UV LED (3.4 eV) – kills the signal, leakage current increases at high intensities.

No increase in current observed for undamaged diamond. Diamond bandgap is 5.5eV = 225nm



First steps of systematic study of illumination were done. So far:

Different wavelength give different results

Intensity of illumination is important.

- There is a saturated value to the effect.
- Saturation does not depend on the amount of damage.
- Short wavelength light produces increase in leakage current.

Probably could be used in practice for example in BCM

Looks like interaction with different trapping levels, but input from theoretical side needed. Suggestions are welcome to possible experiments. What about pCVD?



Backup



For comparison purposes only

The light power in the LED beam spot was measured by Advatec optical power meter.

I tried to keep the beam spot on diamond under study to the same size for all LEDs. No idea how much of the actual beam power was coupled to the sample.

For comparison, typical light intensity of ambient light in the lab is

~ 100-150 μ W for 10x10mm light sensor.



Light + alt HV

So14-04alt 320 um **100** 300 90 LED on 80 250 70 200 _ 60 ш % ш́ 50 СС 150 ပ္ပိ 40 Alt HV, 500V 100 30 1 Hz 20 50 10 0[⊨]0 0 10 15 20 25 30 35 5 Time, min

Alt. Voltage + RL is even better.

2013 fast test, not repeated so far



No source

So14-10 325 um

